NCS2302

Headset Detection Interface with Send/End Detect

The NCS2302 is a compact and cost effective headset detection interface IC. It integrates several circuit blocks to detect the presence of a stereo headset with a microphone and whether the send/end button has been pressed. The NMOS transistor on the MIC pin mutes the signal when the headset is not present. The built in resistor divider provides the reference voltage for detecting the left audio channel. When L_DET and GND_DET are pulled low, the logic low output of the OR gate indicates the headset has been connected properly and the MIC pull−down is disabled. A comparator is integrated for detecting the send/end button press. The NCS2302 comes in a space−saving UQFN10 package (1.4 x 1.8 mm).

Features

- Wide Supply Voltage Ranges:
  For Headset Detection Circuit: V_{DD} = 1.6 V to 2.5 V
  For S/E Comparator Circuit: V_{DD2} = 1.6 V to 2.8 V
- Low Quiescent Supply Current: 17 μA typical
- Low Impedance MIC Pull−Down Reduces Pop & Click Noise: $R_{DS(ON)}$ = 0.45 Ω Typical
- Space Saving UQFN10 Package
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Cell Phones, Smartphones
- Tablets
- Notebooks

ON Semiconductor®

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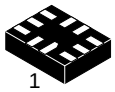
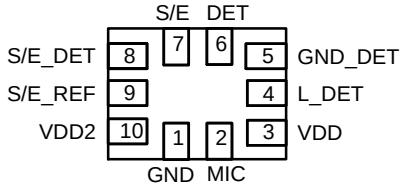


UQFN10
MU SUFFIX
CASE 488AT

MARKING DIAGRAM

AQ = Specific Device Code
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

PIN DIAGRAM



Top View

ORDERING INFORMATION

Device	Package	Shipping†
NCS2302MUTAG	UQFN10 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

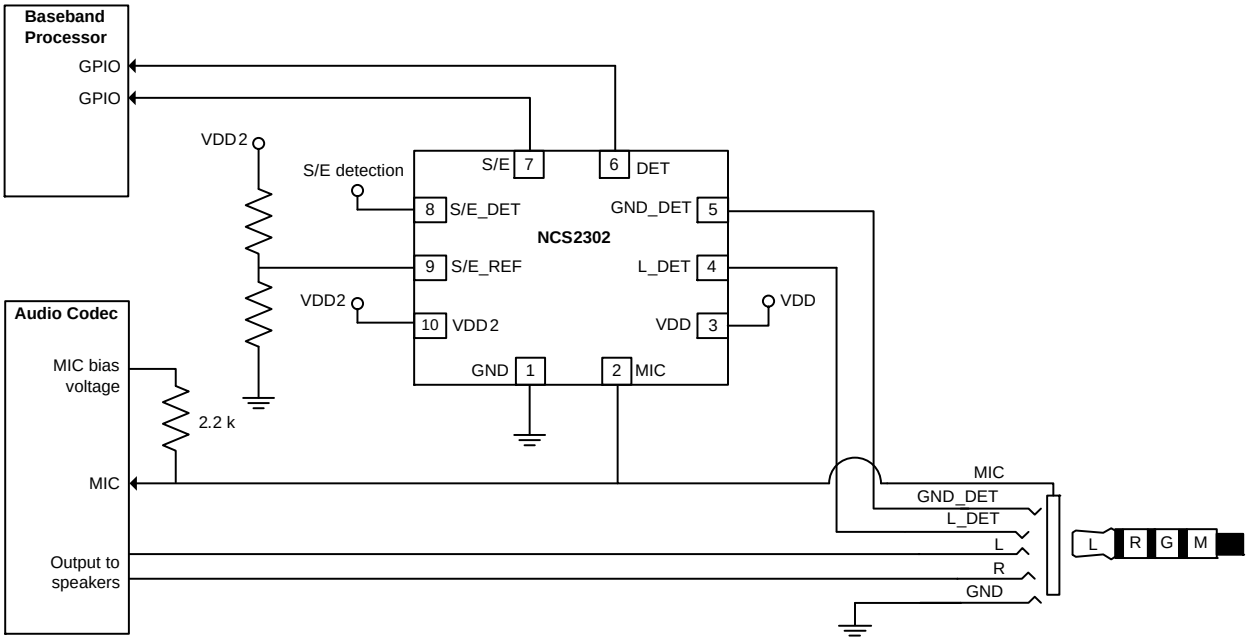


Figure 1. Simplified Application Schematic

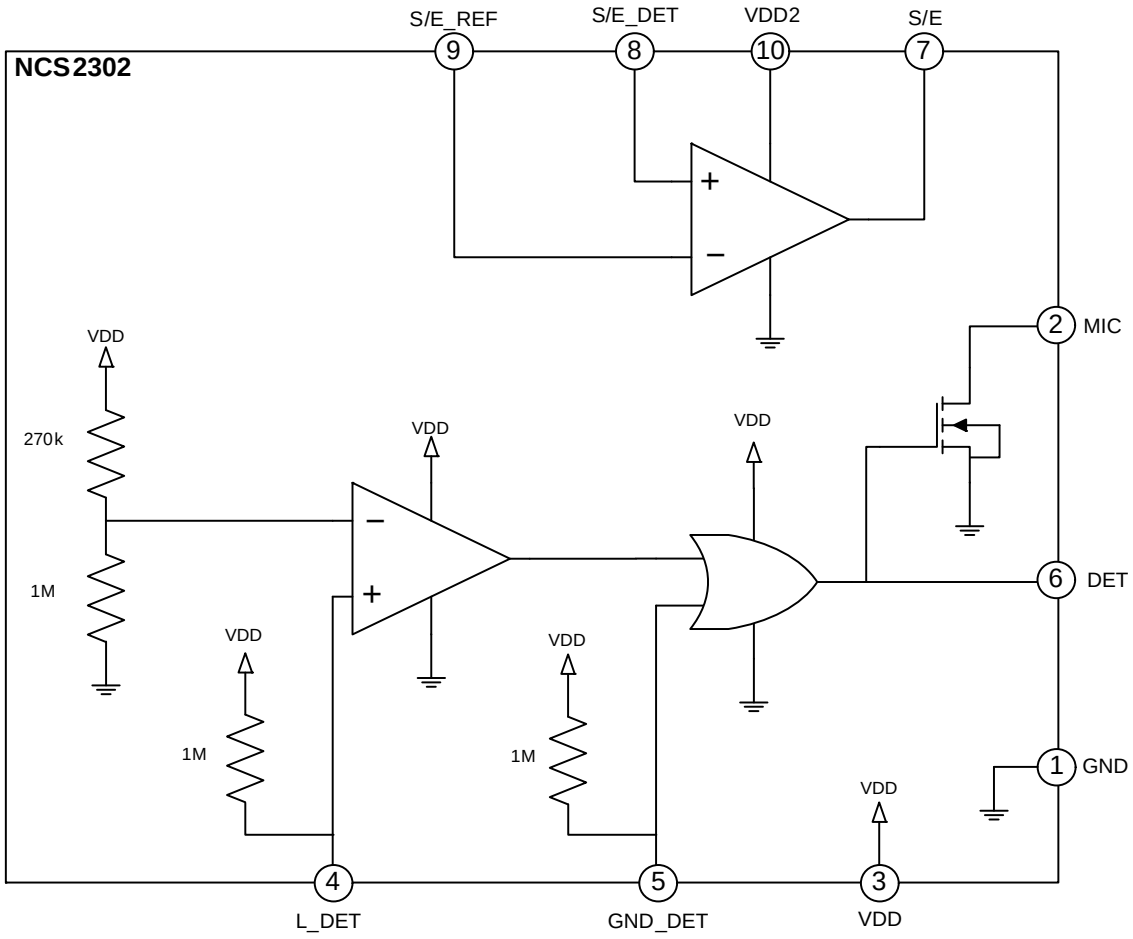


Figure 2. Block Diagram

Table 1. OUTPUT LOGIC

Inputs		Outputs		
L_detect	**GND_detect**	**DET**	**MIC**	**Headset**
0	0	0	1 (external pull−up)	Detected
0	1	1	0	Not Detected
1	0	1	0	
1	1	1	0	

Table 2. PIN DESCRIPTION

Pin	Name	Type	Description
1	GND	Power	Connects to system ground.
2	MIC	Output	The open drain MIC pin is connected to the audio jack MIC pin. The MIC pin will pull low when the headset is not connected. When the headset is detected, the internal pull−down is disabled and the external pull−up biases the microphone.
3	VDD	Power	Supply voltage pin for headset detection circuit. A bypass capacitor of 0.1 μF is recommended as close as possible to this pin.
4	L_DET	Input	Connect to audio jack L_DET. This pin is pulled low when the headset is present.
5	GND_DET	Input	Connect to audio jack GND_DET. This pin is pulled low when the headset is present.
6	DET	Output	Indicates whether headset has been detected. Headset is detected when DET is low.
7	S/E	Output	Indicates whether send/end button press has been detected. Button press is detected when S/E is low.
8	S/E_DET	Input	Non−inverting input of the comparator detects whether the send/end button has been pressed.
9	S/E_REF	Input	Inverting input of the comparator sets a voltage reference with an external resistor divider
10	VDD2	Power	Supply voltage pin for S/E detection comparator. A bypass capacitor of 0.1 μF is recommended as close as possible to this pin.

Table 3. ABSOLUTE MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Supply Voltage Range of Headset Detection Circuit	V_{DD}	0 to 2.75	V
Supply Voltage Range of S/E Detection Comparator	V_{DD2}	0 to 2.95	V
Input Pin Voltage Range (L_DET, GND_DET)	V_{IN}	−0.1 to V_{DD} + 0.1	V
Input Pin Voltage Range (S/E_REF, S/E_DET) (Note 4)	V_{IN}	−0.1 to min(V_{DD2} + 0.6, 3.3)	V
MIC Output Pin Voltage Range	V_{MIC}	0 to 6.0	V
Max Current on MIC Pin	I_{MIC}	2	mA
Maximum Junction Temperature	$T_{J(max)}$	+125	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Latch−up Current (Note 2)	I_{LU}	800	mA
Moisture Sensitivity Level (Note 3)	MSL	Level 1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
2. Latch−up Current tested per JEDEC standard: JESD78
3. Moisture Sensitivity Level tested per IPC/JEDEC standard: J−STD−020A
4. The maximum voltage on the S/E_REF and S/E_DET pins must be the lesser of V_{DD2} + 0.6 and 3.3 V.

Table 4. RECOMMENDED OPERATING RANGES

Rating	Conditions	Symbol	Min	Typ	Max	Unit
Power Supply Voltage	Headset Detection Circuit	V_{DD}	1.6	1.8	2.5	V
	S/E Detection Comparator	V_{DD2}	1.6		2.8	V
Input Voltage	L_DET, GND_DET	V_{IN}	0		V_{DD}	V
	S/E_DET, S/E_REF		0		V_{DD2}	V
Input Transition Rise or Fall Rate	GND_DET pin	$\Delta t / \Delta V$	0		10	ns/V
MIC Bias Voltage		V_{MIC}	0		2.95	V
Ambient Temperature		T_A	−40		85	°C
Junction Temperature		T_J	−40		125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 5. ELECTRICAL CHARACTERISTICS Typical values are referenced to T_A = 25°C, V_{DD} = 1.8 V, V_{DD2} = 2.1 V, unless otherwise noted. Min/max values apply from T_A = −40°C to 85°C, unless otherwise noted. (Notes 5, 6)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Units
SUPPLY CHARACTERISTICS						
Quiescent Supply Current	Headset Detection Circuit, V_{GND_DET} = 1.8 V, V_{L_DET} = 1.8 V	I_{DD}		7	8.5	μA
	S/E Detection Comparator, V_{SE_REF} = 0 V, V_{SE_DET} = 2.1 V	I_{DD2}		10	12.5	μA
INPUT CHARACTERISTICS OF L_DET						
Voltage Input Low		V_{IL}			1.33	V
Voltage Input High		V_{IH}	1.5			V
Propagation Delay to DET	C_{out} = 15 pF, GND_DET = 0 V, L_DET = 1.31 V to 1.52 V	t_{pLH}, t_{pHL}		45		ns
Low to High Propagation Delay to MIC	C_{out} = 15 pF, GND_DET = 0 V, L_DET = 1.31 V to 1.52 V, R_{PU} = 2.2 kΩ, MIC bias = 2.3 V	t_{pLH}		230		ns
High to Low Propagation Delay to MIC	C_{out} = 15 pF, GND_DET = 0 V, L_DET = 1.31 V to 1.52 V, R_{PU} = 2.2 kΩ, MIC bias = 2.3 V	t_{pHL}		30		ns
Low Voltage Input Bias Current	V_{L_DET} = 0 V	I_{IL}		1.8		μA
High Voltage Input Leakage	V_{L_DET} = 1.8 V	I_{IH}		2.4		nA
Input Capacitance	f = 1 MHz	C_{IN}		3		pF
INPUT CHARACTERISTICS OF GND_DET						
Voltage Input Low		V_{IL}			0.63	V
Voltage Input High		V_{IH}	1.17			V
Low to High Propagation Delay to DET	C_{out} = 15 pF, R_L = 1 MΩ, L_detect = 0 V, GND_detect = 1.8 to 0 V	t_{pLH}		30		ns
High to Low Propagation Delay to DET	C_{out} = 15 pF, R_L = 1 MΩ, L_detect = 0 V, GND_detect = 0 to 1.8 V	t_{pHL}		16		ns
Low Voltage Input Bias Current	V_{GND_detect} = 0 V	I_{IL}		1.8		μA
High Voltage Input Leakage	V_{GND_detect} = 1.8 V	I_{IH}		2.7		nA
Input Capacitance	f = 1 MHz	C_{IN}		3		pF

5. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.
6. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

Table 5. ELECTRICAL CHARACTERISTICS Typical values are referenced to T_A = 25°C, V_{DD} = 1.8 V, V_{DD2} = 2.1 V, unless otherwise noted. Min/max values apply from T_A = −40°C to 85°C, unless otherwise noted. (Notes 5, 6)

Parameter	Test Conditions	Symbol	Min	Typ	Max	Units
OUTPUT CHARACTERISTICS OF DET						
Voltage Output Low	I_{OH} = 0.1 mA	V_{OL}			0.1	V
Voltage Output High	I_{OH} = −0.1 mA	V_{OH}	1.6			V
Rise Time	C_{OUT} = 15 pF, R_L = 1 MΩ	t_{rise}		50		ns
Fall Time	C_{OUT} = 15 pF, R_L = 1 MΩ	t_{fall}		28		ns
INPUT CHARACTERISTICS OF S/E_REF AND S/E_DET						
Propagation Delay to S/E	C_{out} = 15 pF, V_{CM} = mid−supply, 100 mV overdrive	t_{pLH}, t_{pHL}		50		ns
Input Leakage	V_{CM} = 0.9 V	I_{IL}		150		pA
Input Capacitance	S/E_DET, f = 1 MHz	C_{IN}		3		pF
	S/E_REF, f = 1 MHz			11		
OUTPUT CHARACTERISTICS OF S/E						
Voltage Output Low	I_{OH} = 0.1 mA	V_{OL}			0.1	V
Voltage Output High	I_{OH} = −0.1 mA	V_{OH}	1.9			V
Rise Time	C_{OUT} = 15 pF, R_L = 1 MΩ	t_{rise}		30		ns
Fall Time	C_{OUT} = 15 pF, R_L = 1 MΩ	t_{fall}		18		ns
CHARACTERISTICS OF MIC						
Drain−Source On Resistance of NMOS	I_{MIC} = 1 mA	$R_{DS(ON)}$		0.45	1.2	Ω

5. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.
6. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

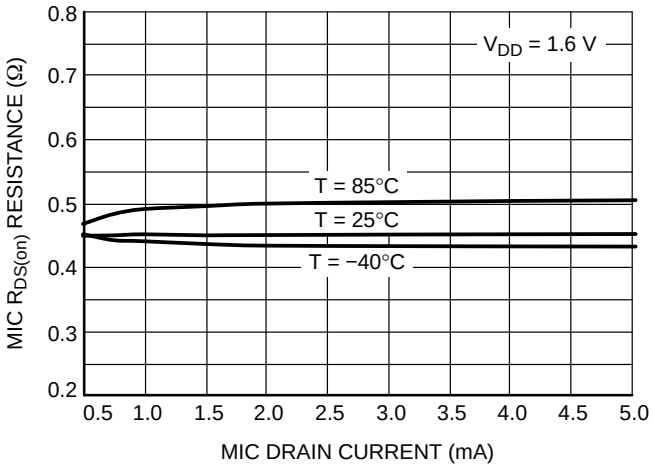


Figure 3. MIC On Resistance vs. Drain Current at V_{DD} = 1.6 V

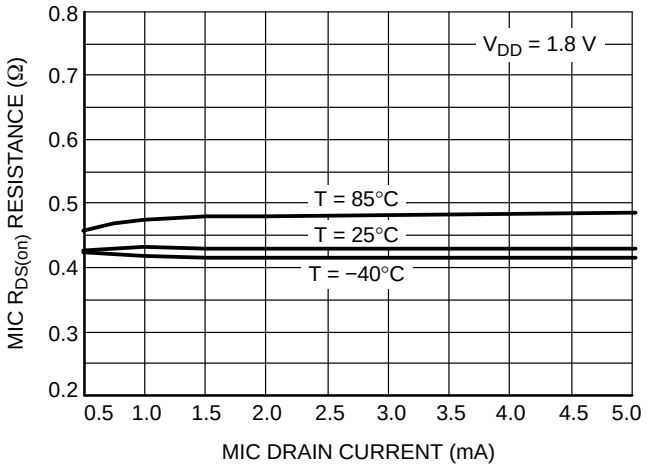


Figure 4. MIC On Resistance vs. Drain Current at V_{DD} = 1.8 V

TYPICAL CHARACTERISTICS

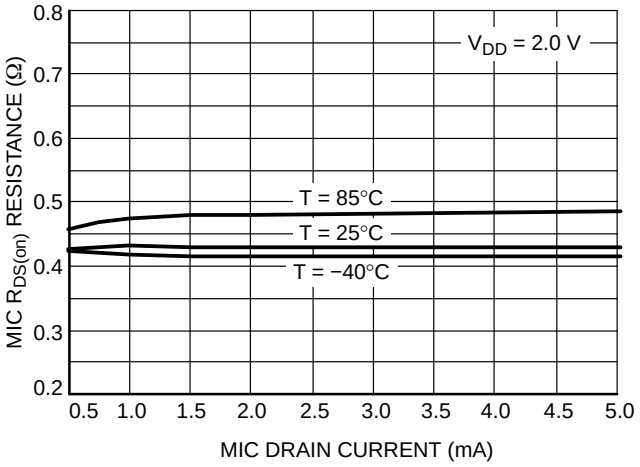


Figure 5. MIC On Resistance vs. Drain Current at V_{DD} = 2.0 V

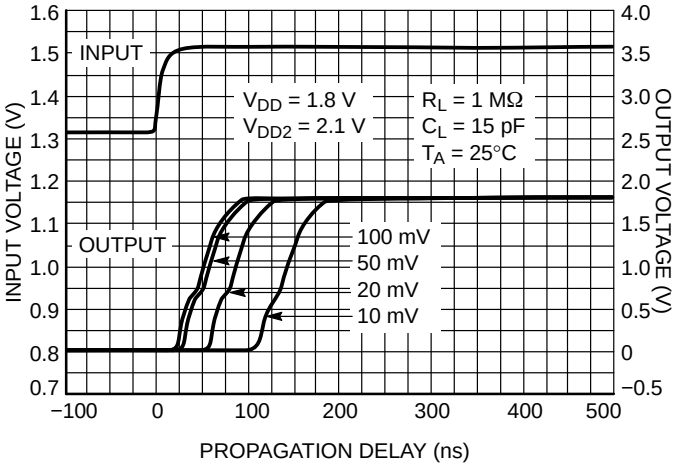


Figure 6. Low to High Propagation to DET with Changing Input Overdrive of L_DET

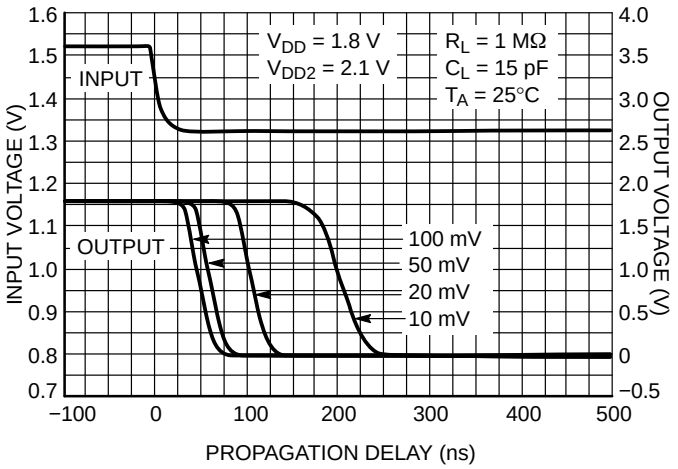


Figure 7. High to Low Propagation to DET with Changing Input Overdrive of L_DET

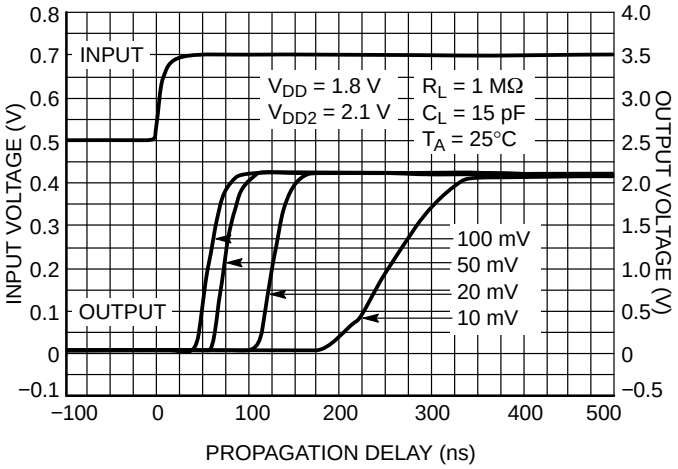


Figure 8. Low to High Propagation to SE with Changing Input Overdrive of SE_DET

TYPICAL CHARACTERISTICS

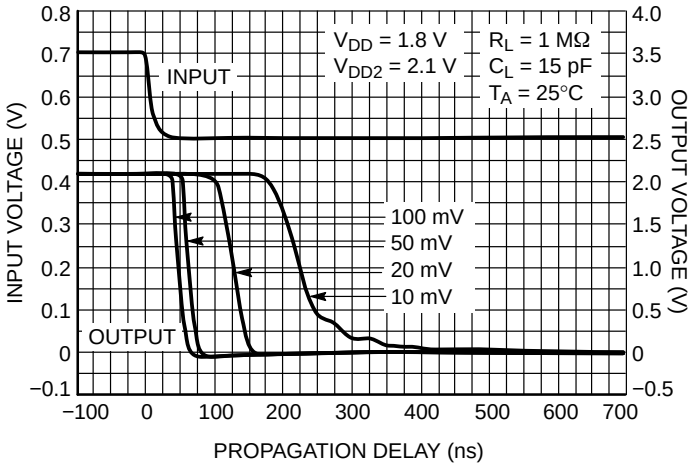


Figure 9. High to Low Propagation to SE with Changing Input Overdrive of SE_DET

APPLICATIONS INFORMATION

Supply Voltages

The NCS2302 works with a wide range of supply voltages. The main headset detection circuitry power supply can range from V_{DD} = 1.6 V to 2.5 V. The send/end button press detection circuit can be powered from V_{DD2} = 1.6 to 2.8 V. V_{DD} should be powered up before V_{DD2}. The send/end detection comparator will not be functional unless V_{DD} and V_{DD2} are both applied. V_{DD2} can be connected to V_{DD} or to a separate supply voltage, such as the MIC bias voltage. Decoupling capacitors of 0.1 μF should be placed as close as possible to each power supply pin. Since the NCS2302 has built in latch−up immunity up to 800 mA, series resistors are not recommended on VDD or VDD2.

Audio Jack Detection

The NCS2302 is designed to simplify the detection of a stereo audio connector with a microphone contact. When the headset is not connected, the internal pull−up resistors on L_DET and GND_DET pull those pins high. When the headset is connected to the switched audio jack, the headset ground and left audio channel trigger L_DET and GND_DET to logic low.

The NCS2302 can work with either the CTIA or OMTP standard. In order to support both standards simultaneously, a cross point switch and additional circuitry is necessary to detect and swap the ground and microphone pins.

Send/End Button Press Detection

A second integrated comparator allows the send/end signal to be compared with a reference voltage to detect whether the send/end button has been pressed.

MIC Pin Biasing

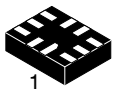
The typical application schematic in Figure 1 shows the recommended 2.2 kΩ pull−up resistor to the MIC bias voltage. The MIC bias voltage can exceed V_{DD} and can go as high as 2.95 V. When the headset is not detected, the internal NMOS transistor is enabled to mute the MIC signal. In the typical application scenario with a 2.2 kΩ pull−up to a 2.1 V MIC bias voltage, the MIC pin is pulled to 1 mV when the headset is not present. The internal NMOS transistor is optimized to sink up to 2 mA of current, allowing some flexibility in the selection of the pull−up resistor and MIC bias voltage.

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

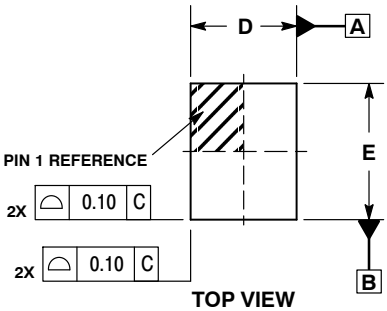
ON Semiconductor®

UQFN10 1.4x1.8, 0.4P
CASE 488AT−01
ISSUE A

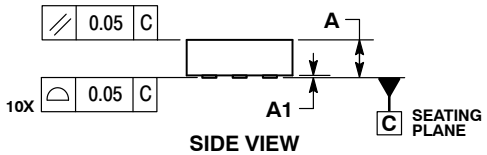
DATE 01 AUG 2007



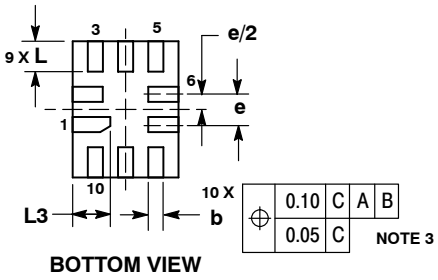
SCALE 5:1



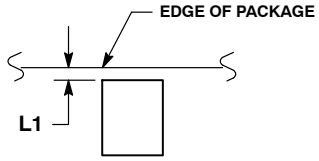
TOP VIEW



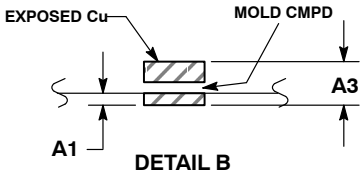
SIDE VIEW



BOTTOM VIEW



DETAIL A
Bottom View
(Optional)

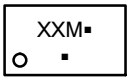


DETAIL B
Side View
(Optional)

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.45	0.60
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.40 BSC	
E	1.80 BSC	
e	0.40 BSC	
L	0.30	0.50
L1	0.00	0.15
L3	0.40	0.60

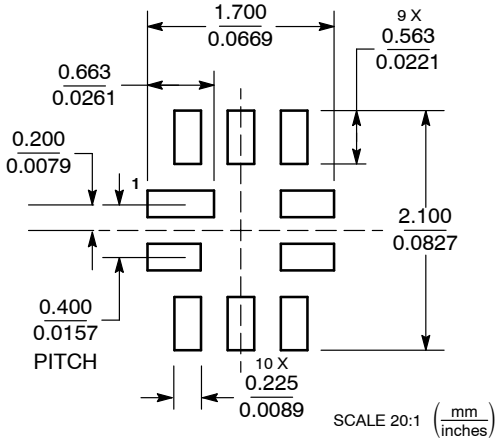
GENERIC MARKING DIAGRAM*



XX = Specific Device Code
M = Date Code
▪ = Pb−Free Package
(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present.

MOUNTING FOOTPRINT



SCALE 20:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

DOCUMENT NUMBER:	**98AON22493D**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red.
DESCRIPTION:	**10 PIN UQFN, 1.4 X 1.8, 0.4P**	**PAGE 1 OF 1**

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
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For additional information, please contact your local Sales Representative

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